

Index

a

absorption coefficient 6–7, 9, 10, 13, 115, 310
 acids, PEDOT:PSS 204
 additives, PEDOT:PSS 203
 Ag grid/PEDOT:PSS 208
 Ag nanowires (NW)
 PEDOT:PSS 210–212
 successive multistep growth 109
 synthesis of 108–110
 TCF
 adhesiveness 123–124
 color 119–120
 fabrication of 110–112
 haze factor 117–119
 pattern 112–114
 roughness 121–123
 scanning electron microscopy 119
 stability 124–126
 transparency and conductivity 115–117
 uniformity 120–121
 α CD-containing polyacrylamide (α CD-PAAm) 197
 Al:ZnO (AZO) 94
 angle-resolved photoemission spectroscopy (ARPES) 16
 annular dark-field scanning transmission electron microscopy (ADF-STEM) 170, 172
 anode
 buffer layer 308–309
 transparent electrode 303–304

aqueous solutions 82
 CBD 81–82
 SnO₂ 90–92
 ZnO 88
 arc-discharge method 155–156
 armchair carbon nanotube 143, 147, 148

b

bandgap renormalization (BGR) 41
 bis (ethylenedioxy)tetrathiafulvalene (BEDO-TTF) 199
 Born-von Kármán periodic boundary conditions 147
 Brillouin zone (BZ)
 graphene 146
 graphene sheet 139
 nanotube 146, 147
 buffer layer
 anode 308–309
 cathode 310
 Burstein–Moss shift (BMS) 34, 41, 51
 B:ZnO (BZO) 94

c

cadmium oxide (CdO) 17, 34, 35, 82, 93
 camphorsulfonic acid (CSA) 196, 197
 carbon-based composites
 applications 216–217
 carbon nanotubes 213–215
 graphene 215–216
 graphene oxide 215–216
 carbon nanotubes (CNT) 25, 213
 arc-discharge method 155

- carbon nanotubes (CNT) (*contd.*)
 - carbon atoms 136
 - chemical vapour deposition 156
 - components of 135
 - electronic properties of 146–151
 - graphene 137–142
 - laser ablation 156
 - mechanical properties 151–152
 - structure of 142–146
 - thermal properties 152–155
 - cathode
 - buffer layer 310
 - transparent electrode 309–310
 - chemical bath deposition (CBD)
 - CdO 93
 - definition of 81–82
 - low temperature post-deposition treatment 93–94
 - In₂O₃ 92
 - principles of 81
 - SnO₂ 90–92
 - TCO devices 94–96
 - ZnO 82–90
 - chemical vapour deposition (CVD) 20, 94, 156
 - graphene 174
 - GTCs 170–171
 - colloidal method 347–348
 - complementary metal oxide semiconductors (CMOS) 176
 - composite films 122, 197–199, 210–213, 215
 - conducting polymeric material 4
 - conductive metal oxides 34, 82
 - conductive polymer 4, 18, 193, 199, 203, 216, 304
 - crystallographic structure
 - ITO 38–42
 - SnO₂ 47–50
 - TiO₂ 50–56
 - ZnO 42–47
 - crystal structure 43, 49, 51, 55, 92, 136, 273, 317, 319, 324
 - cubic close-packed lattice (ccp) 319
 - Cu nanowires (CuNWs) 105, 107, 108, 110, 124, 125, 212
 - Cu(In,Ga)Se₂ (CIGS) 94–96
 - 4-*n*-pentyl-4'-cyanobiphenyl (5CB) 342, 343
- d**
- density-functional calculations (DFT) 33, 39, 44, 49
 - density of states (DOS) 9, 16, 44, 141, 149, 150, 175, 322
 - dibutyl phthalate (DBP) 123
 - dielectric/metal/dielectric (DMD) 304–306
 - dimethylformamide (DMF) 204
 - 1,3-dimethyl-2-imidazolidinone (DMI) 204
 - dimethyl sulfoxide (DMSO) 196, 203, 204, 208, 210, 211, 215
 - Dirac point graphene 167
 - dodecylbenzene sulfonic acid (DBSA)-doped PANI 197
 - Drude–Boltzmann transport theory 8
 - dye sensitized solar cells (DSSCs) 180, 181, 217, 317, 326–331
 - dye molecular composition 327
 - electronic process 326
 - molecule dyes in 328
 - titanium dioxide
 - chemical modification 324–326
 - doping 324
 - electronic considerations 320–321
 - immobilize sensitizer molecules 326–329
 - optical features 322–323
 - photoelectrochemical cells 329–331
 - polymorphs of 317
 - structural properties 319–320
- e**
- electrical contacts
 - circular shape measuring sample 249–250
 - square shape measuring sample 250–252
 - electrical parameters, SnO₂ 48
 - electrical properties

- inhomogeneity 255, 257
- ITO 38–42
- TiO₂ 50–56
- van der Pauw method 248
- ZnO 42–47
- electrochemical polymerization 201–202
- electrochromic (EC) foil
 - color–bleach dynamics 278
 - construction of 275, 276
 - ITO nanoparticles 280
 - mid-luminous transmittance 276, 278
 - PEI–LiTFSI 279
 - roll-to-roll web coating 281
 - spectral transmittance 276, 277
- electrochromic oxide-based materials
 - characterization of 267–268
- EC foil
 - color–bleach dynamics 278
 - ITO nanoparticles 280
 - mid-luminous transmittance 276, 278
 - PEI–LiTFSI 279
 - principle construction of 275, 276
 - roll-to-roll web coating 281
 - spectral transmittance 276, 277
- functional principles 268–270
- nanostructure 270–272
- optical properties 272–275
- thin films 282–285
- electrode interface 311–312
- electroless deposition 81, 92, 108
- electroluminescence 301
- electronic properties, CN 146–151
- electronic transport parameters 7–9
- electron mobility 8, 24, 34, 45, 59, 60, 63, 67
- electron paramagnetic resonance (EPR) 322–323
- electrooptical parameters 345, 346
- energy-dispersive X-ray spectroscopy 11
- energy-efficient glazing 266
- ethylene propylene diene monomer (EPDM) 216
- extended X-ray absorption fine structure (EXAFS) 13–15
- f**
 - face centered cubic lattice 137
 - Fermi level 9, 16, 22, 23, 44, 60, 146, 148, 149, 151, 175, 180
 - figure of merit (FoM) 9
 - electrooptical parameters 345–346
 - metal nanowire 115
 - optical, electrical values 219
 - transparent conductive polymers 194
 - finite-element-method (FEM) 251, 252, 254–256, 260
 - Fourier transform IR (FTIR) 12
 - functionalization of reduced graphene oxide (f-rGO) 216
- g**
 - gallium arsenide (GaAs) 180, 182, 252
 - galvanostatic rejuvenation 284, 285
 - gate field-effect transistors (GFETs) 178, 180
 - gel-glass-dispersed liquid crystals (GDLC) 342
 - preparation of 354
 - sol-gel materials 353–355
 - sol-gel technique 352–353
 - 3-glycidoxypolytrimethoxysilane (GPTMS) 197
 - grain boundaries (GBs) 34, 35, 45, 59, 60, 64, 65, 93, 170, 273
 - graphene (G)
 - Ag nanoparticles 23
 - Brillouin zone 147
 - carbon-based composites 215–216
 - carbon nanotubes 138
 - CVD 20
 - Dirac point 167
 - doped graphene 21
 - engineering work function 175–176
 - GO 19–21
 - metal atoms 22
 - n-type (p-type) 22
 - PVD 23

graphene (G) (*contd.*)

TCOs 165

2D carbon material 165

2D layer 143

graphene-based hybrid layers 21

graphene oxide (GO) 12, 19–21, 23,
123, 124, 170, 213–216

graphene–rubber hybrid electrode 216

graphene transparent conductors
(GTCs)

advantages 166

applications

photodetectors 178–180

photovoltaics 180–182

characterization of 174–175

heterostructures 175–178

intrinsic, physical properties
167–169

synthesis

chemical vapor deposition
170–171

direct growth 171–173

graphene solution 169–170

gray-scale transmittance function 345

grazing incidence spraying (GIS) 113

h

Hall coefficient 8, 9, 250, 259

Hall effect

measuring samples 248

relative measurement errors 250

resistances 248

weighting function 254

ZnO 259–260

hexagonal close-packed lattice (hcp)
319

hexamethylenetetramine (HMTA) 83,
92

highest occupied molecular orbital
(HOMO) 6, 16, 303

i

indium oxide (In_2O_3) 92

crystallographic structure 38–39

electrical parameters 41

electrical properties 39–40

optical properties 40–42

indium-tin-oxide (ITO)

anode 303–304

electrical values of 195

TCO 35

indium-zinc-oxide (IZO) 38, 303, 304,
310

infrared spectroscopy 11–12

inhomogeneity

semiconductor electrical property
254

ZnO 259–260

inorganic transparent electrodes 3

$\text{In}_2\text{O}_3:\text{Sn}$ (ITO) 3

in-situ polymerization 200–201

intensity-modulated photocurrent
spectroscopy (IMPS) 326

intrinsic zinc oxide (i-ZnO) layer 94

ionized impurity scattering 33, 44, 45,
59, 60

I

laser ablation 155, 156

light-shutter devices based LC 342

liquid crystal (LC)

coda 356

elastic distortion 340

electrooptical parameters 345–346

GDLC

sol-gel materials 353–355

sol-gel technique 352–353

indium tin oxide 342

lyotropic 338, 339

mesophase 338

microscopic capsules 355

molecule 339

4-*n*-pentyl-4'-cyanobiphenyl 342

optical anisotropy 342

PDLC

colloidal method 347–348

E7 component 346

PIPS 348–351

SIPS 348

TIPS 348

polymer-stabilized liquid crystals
351

smart-window devices 342–344
 surface anchoring 341
 thermotropic 338
 liquid crystal displays (LCDs) 3, 34,
 302, 312
 liquid phase deposition (LPD) 81, 91,
 92
 lowest unoccupied molecular orbital
 (LUMO) 6, 309, 311
 lyotropic liquid crystals 338, 339

m

magnetic flux density 248
 metal nanowires 18
 OLED 107
 synthesis of 105–108
 TCF
 adhesiveness 123–124
 color 119–120
 fabrication of 110–112
 haze factor 117–119
 pattern 112–114
 roughness 121–123
 scanning electron microscopy
 119
 stability 124–126
 transparency and conductivity
 115–117
 uniformity 120–121
 metal-organic chemical vapour
 deposition (MOCVD) 34, 61
 metal-polypyridine complexes 327
 metal-to-ligand charge transfer (MLCT)
 325
 molecular-beam epitaxy (MBE) 34, 57,
 61
 molecular orbital energy diagram 321
 multi wall carbon nanotubes
 (MWCNTs)
 carbon nanotubes 213–215
 electronic properties 149
 nanotubes 142–146
 thermal properties 150, 151

n

nanoscale grid pattern 18

N-methyl-4(4'-formylstyryl) pyridinium
 methosulfate acetal 113
 n-type semiconductor 39, 44, 255, 259,
 303

o

optical density (OD) 7, 112, 113
 optical properties
 characterization of 267–268
 electrochromic oxide-based materials
 272–275
 ITO 40–42
 SnO₂ 48
 TiO₂ 55–56
 ZnO 46–47
 organic electroluminescent device 301
 organic-inorganic hybrid materials
 352, 354
 organic light-emitting diodes (OLEDs)
 94, 107, 217, 301
 anode 303–304
 buffer layer, anode 308–309
 cathode 309–311
 conductive polymer 304
 DMD 304–307
 liquid crystal display 302
 organic/electrode interface 311–312
 structure of 302
 transparent electrode 312–314
 organic-metal-organic (OMO) 17, 209
 organic photovoltaics (OPVs) 3, 180
 overcoating layer (OCL) 113, 124, 212
 oxidative chemical vapor deposition
 (o-CVD) 200, 201
 oxidative polymerization 200
 oxide electrodes-amorphous films
 17–18
 oxide semiconductor 308

p

PANI-poly(2-acrylamido-2-methyl-1-
 propanesulfonic acid) 197
 photodetectors 167, 175, 177–180
 photoelectric effect 15
 photoelectrochemical cells 317,
 329–331

- photoelectrochemical device,
 - water-splitting reaction 330
 - photoelectrolytic device, water oxidation reaction 330
 - photoluminescence (PL) 259
 - photovoltaics 3, 5, 17, 165, 180–182
 - physical vapor deposition (PVD) 19, 23, 303, 318
 - plasma-assisted deposition method 34
 - point of zero charge (PZC) 87
 - polyaniline (PANI) 194, 196–197, 304
 - polycarbazole (PCz) 199
 - polycrystalline film 34, 35, 44, 45, 59, 63, 65, 67
 - poly(diallyldimethylammonium chloride) (PDDA) 124
 - polydimethylsiloxane (PDMS) 123
 - poly(4,4-dioctylcyclopentadithiophene) 199
 - polyelectrolyte complexes (PEC) 202
 - poly(3,4-ethylenedioxythiophene) (PEDOT) 200, 326
 - poly(3,4-ethylenedioxithiophene):
 - polystyrenesulfonate (PEDOT:PSS) 4, 19, 118, 304
 - acids 204
 - Ag grid 208–210
 - AgNW 210–212
 - electrical characteristics 205
 - formulations 203
 - hole injection layer 308
 - PEDOT:pTS 207
 - salts, ionic liquids, zwitterions 204–207
 - solvents and additives 203–204
 - polyethyleneimine-lithium
 - bis(trifluoromethylsulfonyl) (PEI-LiTFSI) 279
 - polyethylene naphthalate (PEN) 17, 123, 126, 199, 205
 - polyethylene terephthalate (PET) 11, 112, 195, 268
 - polyethylenimine ethoxylated (PEIE) 310
 - polymer-dispersed liquid crystal (PDLC)
 - colloidal method 347–348
 - LC dispersion device 342–344
 - PIPS 348–351
 - SIPS 348
 - TIPS 348
 - ultraviolet damage 350
 - polymeric liquid crystal devices (PLCD) 217
 - polymerization-induced phase
 - separation (PIPS) 348–351
 - polymer-metal composites
 - Ag grid/PEDOT:PSS 208–210
 - AgNW/PEDOT:PSS 210–212
 - film composites 212
 - polymer-stabilized liquid crystals (PSLC) 343, 351
 - poly(methylmethacrylate) (PMMA) 123, 196, 197
 - polypyrrole (PPy) 194, 198, 304, 342
 - polypyrrole-poly(vinyl alcohol) (PPy-PVA) 198
 - poly(p-styrene sulfonate-co-acrylic acid sodium) (PSA) 208
 - poly(styrenesulfonic acid) (PSS) 202
 - polythiophene (PTh), thin films 199
 - poly(*N*-vinylcarbazole) (PVK)/Ag/PVK (PAP) 209
 - polyvinylpyrrolidone (PVP) 18, 106, 197
 - p-toluene sulfonate (PEDOT:pTS) 207
 - PVK/Ag/PEDOT:PSS (PAPE) 209
- r**
- Raman defects peak 12
 - Raman spectroscopy 12, 173
 - reduced graphene oxide (rGO-NH₃⁺) 12, 20, 25, 123, 170, 213, 216
- s**
- sbq-PVA 113
 - scanning electron microscopy (SEM) 119, 170
 - Schottky barrier 311, 312
 - Schottky emission 309, 311
 - self-assembled monolayers (SAM) 92
 - sheet density, carriers 8

- sheet resistance (R_s) 3, 7, 8, 10, 17, 18,
 20, 22, 23, 95, 105–107, 115, 117,
 120–123, 174, 194, 195, 197,
 208–213, 215, 216, 219
- silver nanowires (Ag NWs) 18, 219,
 342
- single-layer graphene (SLG) 22, 167,
 216
- single wall carbon nanotubes (SWNTs)
 213–215
 - nanotubes 142–151
 - thermal properties 152–155
- smart-window devices 337, 342–344
 - GDLC 356
- sodium citrate tribasic (SDA) 88
- sodium dodecylbenzenesulfonate
 (SDBS) 215
- solar irradiance spectrum 267, 268
- sol-gel materials 353–355
- sol-gel technique 318, 352, 354
- solvent induced phase separation (SIPS)
 348
- solvents, PEDOT:PSS 203
- spectroscopy
 - Raman and infrared 11–12
 - UPS 15–17
 - XAS 13–15
 - XPS 15–17
- stannous oxide (SnO) 48, 91
- stoichiometric titanium oxides 53
- stoichiometric zinc oxide 44
- structure directing agents (SDA) 83,
 85, 86
- successive multistep growth (SMG)
 109
- sulfonated carbon nanotubes (SCNT)
 213
- sulfonated graphene (S-Gra) 216
- surface enhanced Raman spectroscopy
 (SERS) 183
- synchrotron radiation, XAS 13
- t**
- tetragonal anatase crystal 52
- tetrathiafulvalene (TTF)-tethered
 polymers 199
- thermal conductivity 137, 153–155
- thermally-induced phase separation
 (TIPS) 348
- thermal properties
 - carbon nanotubes 152
 - mechanical 151–152
- thermal roll imprinting (TRI) 208
- thin films
 - electrochromic 282–285
 - properties
 - ITO 57–59
 - SnO₂ 60–63
 - TiO₂ 63–67
 - ZnO 59–60
- thiol-ene photopolymerization 350
- thiol-ene polymerization 349
- Timoshenko beam theory 152
- tin-doped indium oxide (ITO)
 - crystallographic structure 38–39
 - electrical properties 39–40
 - optical properties 40–42
 - thin film 57–67
- tin oxide (SnO₂) 90
 - crystallographic structure 48
 - electrical parameters 48
 - molecular orbital energy diagram
 321
 - optical properties 48–50
 - TCO 35
 - thin film 60–63
- titanium dioxide (TiO₂)
 - chemical modification 324–326
 - crystallographic structure 50–53
 - DSSC 317
 - electrical properties 53–55
 - electronic considerations 320–321
 - immobilize sensitizer molecules
 326–329
 - optical features 322–323
 - optical properties 55–56
 - organometallic dyes 324–326
 - photoelectrochemical cells 329–331
 - structural properties 319–320
 - thin film 63–67
- topological insulators (TIs) 4

- transmittance 5–7, 9, 10, 18, 20, 33, 40, 41, 46, 47, 50, 56, 92, 93, 96, 165, 166, 168, 169, 174, 195–201, 207–209, 213, 215, 216, 275, 276, 278, 279, 281, 283, 285
 - transparent conducting films
 - doped graphene 21–24
 - graphene and GO 19–21
 - metallic nanowires, grids 18–19
 - oxide electrodes-amorphous films 17–18
 - transmittance 6–7
 - transparent conducting oxides (TCO)
 - CNT 24
 - oxide electrodes-amorphous films 17–18
 - spectroscopy 13–15
 - transparent conductive films (TCF) 7
 - AgNWs 106, 107
 - metal nanowires
 - adhesiveness 123–124
 - color 119–120
 - fabrication of 110–112
 - haze factor 117–119
 - pattern 112–114
 - roughness 121–123
 - stability 124–126
 - transparency and conductivity 115–117
 - uniformity 120–121
 - transparent conductive oxides (TCO) 4
 - CBD 89
 - electron orbitals and effective masses 36
 - ITO
 - crystallographic structure 38–39
 - electrical properties 39–40
 - optical properties 40–42
 - thin film 57–67
 - material class of 33, 35
 - of silicon 36
 - SnO₂
 - crystallographic structure 48
 - electrical parameters 48
 - optical parameters 48–50
 - thin film 60–63
 - TiO₂
 - crystallographic structure 50–53
 - electrical properties 53–55
 - optical properties 55–56
 - thin film 63–67
 - ZnO
 - crystallographic structure 43–44
 - electrical properties 44–46
 - optical properties 46–47
 - thin film 59–60
 - transparent conductive polymers
 - carbon-based composites
 - applications 216–217
 - carbon nanotubes 213–215
 - figure of merit 194–195
 - PEDOT:PSS 202–208
 - polyaniline 196–197
 - polymer-metal composites
 - Ag grid/PEDOT:PSS 208–209
 - AgNW/PEDOT:PSS 210–212
 - film composites 212
 - poly(3,4-ethylenedioxythiophene)
 - PEDOT 200–302
 - polypyrrole 198
 - transparent electrodes 3
 - absorption coefficient 6–7
 - anode 303–304
 - buffer layer 308–309
 - cathode 309–310
 - conductive polymer 304
 - DMD 304–307
 - electronic transport parameters 7–9
 - figure of merit 9–11
 - nanowire networks 11
 - OLEDs 312–314
 - organic/electrode interface 311–312
 - TCO 34
 - transmittance 5–6
 - transparent film 3, 4, 212, 216
 - trimethylamine borane (TMBA) 92
- u**
- ultraviolet light-emitting diodes (UV-LEDs) 213

ultraviolet photoelectron spectroscopy (UPS) 15
urban heat islands 266

V

valence band 4, 6, 16, 33, 44, 53, 140, 180, 301, 302, 321, 322
valence band maxima (VBM) 48
van der Pauw method 6, 7, 247
electrical contacts
circular shape measuring sample 249–250
square shape measuring sample 250–252
electrical property measurement 248
finite-element-method 251
inhomogeneity
semiconductor electrical property 254
ZnO 259–260
van der Waals (vdW), heterojunction interface 176
vapor phase polymerization (VPP) 200, 201

W

water-splitting reaction 329, 330
weighting functions 254
wide-bandgap semiconductors 67, 165, 253, 268
Wigner-Seitz cell 139

work function, electronic 16
wurtzite crystal structure 43

X

X-ray absorption near edge structure (XANES) 15
X-ray absorption spectroscopy (XAS)
experiments 13
K-edge Mo XANES 14
K-edge Ti XANES 15
synchrotron radiation 13
X-ray photoelectron spectroscopy (XPS) and UPS 15

Z

Zinc oxide (ZnO)
Al:ZnO 88
ammonia 83
aqueous solutions 88
crystallographic structure 43–44
crystals 85
doping 87
electrical properties 44–46
Ga:ZnO 90
hexamethylenetetraamine 83
methoxyethanol 86
optical properties 46–47
point of zero charge 87
structure directing agent 87
TCO 35
thin film 59–60
zinc ammine based 84

